Synthesis and Properties of Tetrathiafulvalene–Metal Bisdithiolene Macromolecules

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Summary Reaction of tetrasodium tetrathiafulvalenetetrathiolate with transition metal salts leads to the formation of tetrathiafulvalene-metal bisdithiolene oligomers which in the case of the nickel derivative possesses unusually high conductivity (ca. $30 \Omega^{-1} \text{ cm}^{-1}$).

Two well-studied π -systems which display interesting solid state electronic properties are tetrathiafulvalene (TTF),¹ a π -electron donor, and metal bisdithioleneato-complexes,² π -electron acceptors. While studying the chemistry of thiapendione³ (1), we discovered a means of coupling these two π -systems into a single conjugated molecular framework.

Treatment of (1) with trialkyl phosphites provided the dimer dithiapendione (2) which was subsequently treated with base [NaOMe-MeOH or MeLi-tetrahydrofuran (THF)] to give the thermally and air sensitive tetrathiafulvalene-tetrathiolate intermediate (3).[†] Reaction of (3) with transition metal salts (ML_n) led to the precipitation of insoluble, amorphous powders (non-crystalline X-ray powder pattern) with metal: ligand ratio ca. 1:1. The insolubility of these materials precluded rigorous characterization of their structure, but based on the chemistry (see later), and by analogy with the known linear polymers [M(SR)₂]_x (M = Ni or Pd)⁴ and (TTNNi)_x⁵ (TTN = tetrathianaphthalene) a repeating TTF-metal bisdithiolene composition with the oligomeric structure (4) seems reasonable.

In the case of (4; M=Ni), elemental analysis for this stoicheiometry gave: C 18.10, Ni 15.15%; calc. for C₆NiS₈ C 18.10, Ni 15.24%. Spectrophotometric measurements in



† The presence of this intermediate in solution is confirmed by its near-quantitative conversion on treatment with methyl iodide into the independently synthesized tetrathiomethyl-TTF; see ref. 3 for details.

KBr show strong electronic absorptions at 34,500 and 32,250 cm⁻¹, characteristic of the dithiolene and an intense broad absorption in the i.r. region (ca. $2 \mu m$). This latter absorption is characteristic⁶ of the highly conducting crystalline charge-transfer salts, and in fact, the oligomer (4; M = Ni) was found to have the surprisingly high conductivity of ca. $30 \Omega^{-1} \text{ cm}^{-1.7}$ Other transition metal derivatives of (4) displayed lower conductivities (e.g., $M = Cu, ca. 10^{-1} \Omega^{-1} cm^{-1}; M = Fe, ca. 10^{-5}; M = Pt, ca. 10^{-2} and M = Pd, ca. 10^{-3}).$ A more characterizable model system of (4) could be prepared by the reaction of di(trifluoromethyl)tetrathiafulvalenedithiolate8 disodium (5) with nickel acetate followed by treatment with O_2 which precipitates (6). Compound (6) was purified by Soxhlet extraction (PhCl) to give green-black platelets, m.p. >360 °C [v (KBr) 1600 m, 1494m, 1250s, br, 1162s, br, 945w, 915m, 838w, 715m, and 690w cm⁻¹]; satisfactory C, F, Ni, and S

analyses were obtained for this compound. An unusually low-energy electronic absorption at $1.35 \,\mu\text{m}$ ($\epsilon \ ca. \ 10^4$ in Me₂SO) was observed, considerably shifted from the characteristic low-energy absorption $(0.8-1.0 \,\mu\text{m})^2$ found for nickel bis-dithiolene derivatives. The preparation of (6) suggests that the structure proposed for oligomer (4) is reasonable. Compound (6) is insulating; however, this may be due to the presence of strongly electron withdrawing substituents on TTF which greatly decrease its donor properties.

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